

GigaDevice Semiconductor Inc.

FLASH 模拟 EEPROM

应用笔记

AN132

1.0 版本

(2023 年 5 月)

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1. 简介

FLASH 和 EEPROM 都是非易失性储存器，在掉电后数据还会保留。FLASH 和 EEPROM 最大的区别是擦除方式不同，EEPROM 可以按字节进行擦除，但 FLASH 最小擦除单位是页，一页通常包含多个字节甚至几 K 字节。FLASH 和 EEPROM 擦写属性决定了 EEPROM 容量小但擦写寿命比较高，而 FLASH 容量非常大，但擦写寿命短。

在 MCU 主频高的情况下，可以采用 FLASH 模拟 EEPROM 来降低成本。本文介绍了一种采用 FLASH 模拟 EEPROM 的方法，实现了 EEPROM 按字节进行数据修改，可防止复位或掉电产生的数据丢失，当采用的 FLASH 存储空间越大，EEPROM 性能越好。

2. EEPROM 备份区结构

本文以63页DATA FLASH模拟2K字节EEPROM来介绍FLASH模拟EEPROM的方法。

2.1. GD32A50x FLASH 简介

GD32A50x提供高达384KB片上FLASH，其中bank0 256KB，bank1 128KB。基地址和大小如[表2-1. 384KB闪存基地址和大小](#)所示。

表 2-1. 384KB 闪存基地址和大小

闪存块	名称	地址范围	大小(字节)	
主存储闪存块	bank0	第 0 页	0x0800 0000 - 0x0800 03FF	1KB
		第 1 页	0x0800 0400 - 0x0800 07FF	1KB
		第 2 页	0x0800 0800 - 0x0800 0BFF	1KB
		.	.	.
		第 255 页	0x0803 FC00 - 0x0803 FFFF	1KB
	bank1	第 256 页	0x0804 0000 - 0x0804 03FF	1KB
		第 257 页	0x0804 0400 - 0x0804 07FF	1KB
		第 258 页	0x0804 0800 - 0x0804 0BFF	1KB
		.	.	.
		第 383 页	0x0805 FC00 - 0x0805 FFFF	1KB
扩展闪存块	数据闪存	0x0880 0000 - 0x0880 FFFF	64KB	
	备份 EEPROM	-		

2.2. EEPROM 数据备份结构

表 2-2. FLASH 页数据备份存储结构

功能	大小(字节)
EEPROM 页 0	FLASH 页使用标记
	8
	EEPROM 页开始标记
	8
EEPROM 页 1	EEPROM 页结束标记
	8
	EEPROM 数据
	2048
...	FLASH 页使用标记
	8
	EEPROM 页开始标记
	8
...	EEPROM 页结束标记
	8
...	EEPROM 数据
	2048
...	...

功能		大小(字节)
EEPROM 页 n	FLASH 页使用标记	8
	EEPROM 页开始标记	8
	EEPROM 页结束标记	8
	EEPROM 数据	2048

3. FLASH 模拟 EEPROM 方案

3.1. 算法实现

3.1.1. 参数宏

表 3-1. 参数宏

名称	功能
EEPROM_DATA_SIZE	模拟 EEPROM 大小
EEPROM_FLASH_PAGE_NUM	使用的 FLASH 页数
FLASH_PAGE_SIZE	FLASH 页大小
EEPROM_PAGE_SIZE	EEPROM 页大小
EEPROM_PAGE_DW_NUM	每页 EEPROM 包含的双字
EEPROM_PAGE_NUM	一页 FLASH 中包含的 EEPROM 页数
EEPROM_BACKUP_SIZE	EEPROM 备份区大小
EEPROM_BACKUP_END_ADDR	EEPROM 备份区结束地址
EEPROM_BACKUP_START_ADDR	EEPROM 备份区起始地址
EEPROM_PAGE_HEAD_FLAG	EEPROM 起始标记
EEPROM_PAGE_END_FLAG	EEPROM 结束标记
EEPROM_WORK_PAGE_FLAG	FLASH 页使用标记
FLASH_PAGES_PER_EEPROM_PAGE	每页 EEPROM 包含的 FLASH 页数

3.1.2. API 函数

函数 eeprom_init

函数 eeprom_init 用于初始化 EEPROM 备份区，并获取当前正在用于 EEPROM 备份的 FLASH 页相对编号。

表 3-2. EEPROM 初始化

```
void eeprom_init(void)
{
    uint16_t i = 0;
    uint8_t flag_mark_num = 0;
    uint64_t flag_work_page = 0;
    uint8_t check_ff_flag = 0;
    for(i = 0; i < EEPROM_FLASH_PAGE_NUM; i += FLASH_PAGES_PER_EEPROM_PAGE) {
        flag_work_page = REG64(EEPROM_BACKUP_START_ADDR + i * FLASH_PAGE_SIZE);
        check_ff_flag = check_ff(EEPROM_BACKUP_START_ADDR + i * FLASH_PAGE_SIZE,
                               FLASH_PAGE_SIZE * FLASH_PAGES_PER_EEPROM_PAGE);
        /* if the flash is without EEPROM_WORK_PAGE_FLAG but the page is not empty, erase */
    }
}
```

```

the flash page */

    if(((0xfffffffffffffff == flag_work_page) && (0x01 != check_ff_flag)) || ((0xfffffffffffffff != flag_work_page) && (EEPROM_WORK_PAGE_FLAG != flag_work_page))) {
        eeprom_block_erase(EEPROM_BACKUP_START_ADDR + i * FLASH_PAGE_SIZE);
    } else if(REG64(EEPROM_BACKUP_START_ADDR + i * FLASH_PAGE_SIZE) == EEPROM_WORK_PAGE_FLAG) {
        /* find the flash page with EEPROM_WORK_PAGE_FLAG marked */
        current_page = i;
        flag_mark_num++;
    }
}

/* no EEPROM_WORK_PAGE_FLAG is found */
if(flag_mark_num == 0) {
    current_page = 0;
}
if(flag_mark_num > 1) {
    /* the first block is not the marked page */
    if(REG64(EEPROM_BACKUP_START_ADDR) == 0xfffffffffffffff) {
        if(REG64(EEPROM_BACKUP_START_ADDR + current_page * FLASH_PAGE_SIZE + 8 * 2) == EEPROM_PAGE_END_FLAG) {
            /* erase the page whose index is current_page-FLASH_PAGES_PER_EEPROM_PAGE(the forward EEPROM block) */
            eeprom_block_erase(EEPROM_BACKUP_START_ADDR + (current_page - FLASH_PAGES_PER_EEPROM_PAGE)*FLASH_PAGE_SIZE);
        } else {
            /* erase the page whose index is current_page, because EEPROM_PAGE_END_FLAG is not found, and the data is incomplete, discard the data */
            eeprom_block_erase(EEPROM_BACKUP_START_ADDR + current_page * FLASH_PAGE_SIZE);
            current_page -= FLASH_PAGES_PER_EEPROM_PAGE;
        }
    }
    /* the first block is the marked block */
} else {
    /* the marked block is the first block and the last block */
    if(FLASH_PAGES_PER_EEPROM_PAGE != current_page) {
        if(REG64(EEPROM_BACKUP_START_ADDR + 8 * 2) == EEPROM_PAGE_END_FLAG) {
            eeprom_block_erase(EEPROM_BACKUP_START_ADDR + current_page * FLASH_PAGE_SIZE);
            current_page = 0;
        } else {
            eeprom_block_erase(EEPROM_BACKUP_START_ADDR);
        }
    }
}

```

```
/* the marked block is the first block and the second block */
} else {
    if(REG64(EEPROM_BACKUP_START_ADDR + current_page * FLASH_PAGE_SIZE + 8 * 2) == EEPROM_PAGE_END_FLAG) {
        eeprom_block_erase(EEPROM_BACKUP_START_ADDR);
    } else {
        eeprom_block_erase(EEPROM_BACKUP_START_ADDR + current_page * FLASH_PAGE_SIZE);
        current_page = 0;
    }
}
}
}
}
```

函数 eeprom_write

函数 `eeprom_write` 用于索引当前可写的地址，并将数据写到对应 `FLASH` 地址。注意该函数的入参 `ee_addr` 是模拟 EEPROM 地址，范围为 0-135。

表 3-3. EEPROM 写函数

```

uint8_t eeprom_write(uint16_t ee_addr, uint8_t *data, uint16_t size)
{
    uint8_t ee_state = 0x01, i = 0;
    uint32_t block_addr = 0, ee_data_addr = 0;
    uint64_t temp_flag = 0;
    uint16_t tmp_size = 0, addr_tmp = 0;
    uint8_t *p_tmp = data;

    if(ee_addr + size > EEPROM_DATA_SIZE) {
        ee_state = 0x00;
        size = EEPROM_DATA_SIZE - ee_addr;
    }

    eeprom_read(0, (uint8_t *)record_buf, EEPROM_DATA_SIZE);
    tmp_size = size;
    addr_tmp = ee_addr;
    /* refresh the data in EEPROM */
    while(tmp_size--) {
        ((uint8_t *)record_buf)[addr_tmp++] = *p_tmp++;
    }

    /* find the block start address to write data */
    if(0xffffffffffffffff != REG64(EEPROM_BACKUP_START_ADDR) + current_page *
FLASH_PAGE_SIZE + 8)){
        if((EEPROM_FLASH_PAGE_NUM - FLASH_PAGES_PER_EEPROM_PAGE) ==
current_page){

```

```

        current_page = 0;
    }else{
        current_page = current_page + FLASH_PAGES_PER_EEPROM_PAGE;
    }
}

block_addr = EEPROM_BACKUP_START_ADDR + current_page * FLASH_PAGE_SIZE + 8;
ee_data_addr = block_addr + 8 * 2;
temp_flag = EEPROM_WORK_PAGE_FLAG;
if(0 == flash_program(block_addr - 8, &temp_flag, 1)) {
    ee_state = 0x00;
}

/* write the EEPROM_PAGE_HEAD_FLAG */
temp_flag = EEPROM_PAGE_HEAD_FLAG;
if(0 == flash_program(ee_data_addr - 8 * 2, &temp_flag, 1)) {
    ee_state = 0x00;
}

/* write the data */
if(0 == flash_program(ee_data_addr, record_buf, EEPROM_PAGE_DW_NUM)) {
    ee_state = 0x00;
}

/* read back data */
flash_read_word(ee_data_addr, (uint8_t *)record_buf, EEPROM_DATA_SIZE);
tmp_size = size;
addr_tmp = ee_addr;
while(tmp_size--) {
    /* check the data */
    if(((uint8_t *)record_buf)[addr_tmp++] != *data++) {
        ee_state = 0x00;
    }
}

/* write the EEPROM_PAGE_END_FLAG */
if(ee_state == 0x01) {
    temp_flag = EEPROM_PAGE_END_FLAG;
    if(0 == flash_program(ee_data_addr - 8, &temp_flag, 1)) {
        ee_state = 0x00;
    }
}

if(ee_data_addr == block_addr + 8 * 2) {
    if(block_addr == EEPROM_BACKUP_START_ADDR + 8) {
        /* the current page is the last flash page */
        eeprom_block_erase(EEPROM_BACKUP_START_ADDR
(EEPROM_FLASH_PAGE_NUM - FLASH_PAGES_PER_EEPROM_PAGE)*FLASH_PAGE_SIZE);
    } else {
}
}

```

```

/* the current page is not the last flash page */
    eeprom_block_erase(EEPROM_BACKUP_START_ADDR + (current_page -
FLASH_PAGES_PER_EEPROM_PAGE)*FLASH_PAGE_SIZE);
}
}

return ee_state;
}

```

函数 eeprom_read

函数 `eeprom_read` 用于读取 EEPROM 备份区最新的数据。注意该函数的入参 `ee_addr` 是 EEPROM 地址，范围为 0-135。

表 3-4. EEPROM 读函数

```

uint8_t eeprom_read(uint16_t ee_addr, uint8_t *data, uint16_t size)
{
    uint8_t ee_state = 1, i = 0;
    uint32_t page_addr, ee_data_addr;
    /* find the page start address to write data */
    page_addr = EEPROM_BACKUP_START_ADDR + current_page * FLASH_PAGE_SIZE + 8;
    /* locate at the address to read data */
    ee_data_addr = page_addr + 8 * 2;
    if(ee_addr + size > EEPROM_DATA_SIZE) {
        ee_state = 0x00;
        size = EEPROM_DATA_SIZE - ee_addr;
    }
    /* read data */
    flash_read_word(ee_data_addr + ee_addr, data, size);
    return(ee_state);
}

```

3.1.3. 测试结果

测试在 EEPROM 中改写第一个字节共 16 次。写入数据如[图 3-1. 读写数据](#)所示。

图 3-1. 读写数据

```

uint8_t data[2048] = {0x00, 0x01, 0x02, 0x03, 0x04, 0x05, 0x06, 0x07, 0x08, 0x09, 0x0A, 0x0B, 0x0C, 0x0D, 0x0E, 0x0F,
....., 0x10, 0x11, 0x12, 0x13, 0x14, 0x15, 0x16, 0x17, 0x18, 0x19, 0x1A, 0x1B, 0x1C, 0x1D, 0x1E, 0x1F
.....};

```

代码如[表 3-5. 测试 demo](#) 所示。

表 3-5. 测试 demo

```

int main(void)
{
    fmc_unlock();
    ob_unlock();
}

```

```
/* configure the data flash size as 64k */
if(0x10000 != dflash_size_get()){
    ob1_eeprom_parameter_config(OB1CS_DF_64K_EF_0K, OB1CS_EPSIZE_NONE);
    ob_reset();
}
ob_lock();
fmc_lock();
gd_eval_led_init(LED1);
gd_eval_led_init(LED2);
eeprom_init();
eeprom_read(0, data_read, 2048);
for(int i=0; i<16; i++){
    data[0] = i;
    eeprom_write(0, data, 2048);
    eeprom_read(0, data_read, 2048);
    if(SUCCESS != byte_memory_compare(data, data_read, 2048)) {
        gd_eval_led_on(LED2);
        return ERROR;
    }
}
gd_eval_led_on(LED1);
while(1) {
}
}
```

测试结果如[图 3-2. EEPROM 备份区数据](#)所示。

图 3-2. EEPROM 备份区数据

4. 版本历史

表 4-1. 版本历史

版本号.	说明	日期
1.0	首次发布	2023 年 05 月 30 日

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